

APT2012SYCK

2.0 x 1.25 mm SMD Chip LED Lamp



DESCRIPTIONS

- The Super Bright Yellow device is made with AIGaInP (on GaAs substrate) light emitting diode chip
- · Electrostatic discharge and power surge could damage the LEDs
- · It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- · All devices, equipments and machineries must be electrically grounded

FEATURES

- 2.0 mm x 1.25 mm SMD LED, 0.75 mm thickness
- Low power consumption
- Wide viewing angle
- · Ideal for backlight and indicator
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- RoHS compliant

APPLICATIONS

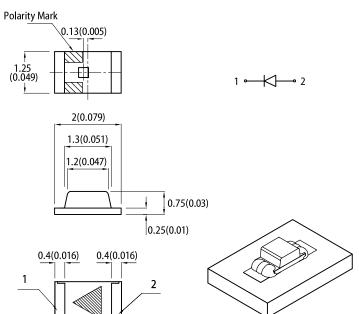
- Backlight
- Status indicator
- · Home and smart appliances
- · Wearable and portable devices
- Healthcare applications

ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices



PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Notes

All dimensions are in millimeters (inches).
 Tolerance is ±0.1(0.004") unless otherwise noted.
 The specifications, characteristics and technical data described in the datasheet are subject to

change without prior notice. The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color	Lens Type	lv (mcd) @ 20mA ^[2]		Viewing Angle ^[1]
Fart Number	(Material)	Lens Type	Min.	Тур.	201/2
APT2012SYCK	Super Bright Yellow (AlGaInP)	Water Clear	80	150	140°

Notes

41/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 2. Luminous intensity / luminous flux: +/-15%.
 3. Luminous intensity value is traceable to CIE127-2007 standards.

Kingbright

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Denemeter	Cumula al	Emitting Color	Value		Unit
Parameter	Symbol	Emitting Color	Typ. Max.		
Wavelength at Peak Emission I_F = 20mA	λ_{peak}	Super Bright Yellow	590	-	nm
Dominant Wavelength I _F = 20mA	λ_{dom} ^[1]	Super Bright Yellow	590	-	nm
Spectral Bandwidth at 50% Φ REL MAX I_F = 20mA	Δλ	Super Bright Yellow	20	-	nm
Capacitance	С	Super Bright Yellow	20	-	pF
Forward Voltage I _F = 20mA	V _F ^[2]	Super Bright Yellow	2.0	2.5	V
Reverse Current ($V_R = 5V$)	I _R	Super Bright Yellow	-	10	μA
Temperature Coefficient of λ_{peak} I_F = 20mA, -10°C $\leq T \leq 85^\circ C$	$TC_{\lambda peak}$	Super Bright Yellow	0.12	-	nm/°C
Temperature Coefficient of λ_{dom} I_F = 20mA, -10°C $\leq T \leq 85^\circ C$	TC _{λdom}	Super Bright Yellow	0.07	-	nm/°C
Temperature Coefficient of $~V_F$ $~I_F$ = 20mA, -10 $^\circ C \leq T \leq 85 ^\circ C$	TCv	Super Bright Yellow	-1.9	-	mV/°C

Notes:

The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd : ±1nm.)
 Thorward voltage: ±0.1V.
 Wavelength value is traceable to CIE127-2007 standards.
 Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

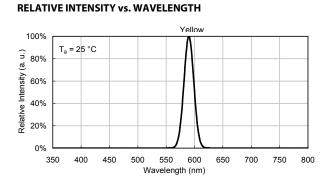
ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	75	mW
Reverse Voltage	V _R	5	V
Junction Temperature	Tj	115	°C
Operating Temperature	T _{op}	-40 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
DC Forward Current	l _F	30	mA
Peak Forward Current	Ι _{FM} ^[1]	175	mA
Electrostatic Discharge Threshold (HBM)	-	3000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	640	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	460	°C/W

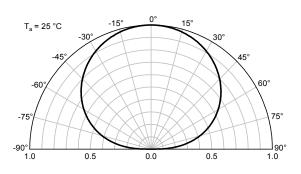
Notes: 1. 1/10 Duty Cycle, 0.1ms Pulse Width. 2. R_{th JA}, R_{th JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad). 3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

Kingbright

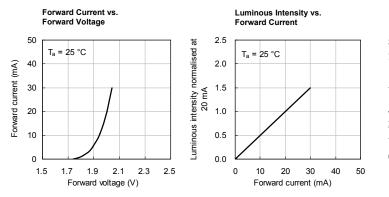
TECHNICAL DATA



SPATIAL DISTRIBUTION

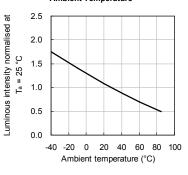


SUPER BRIGHT YELLOW

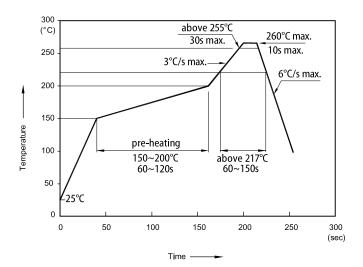


Forward Current Derating Curve 50 Permissible forward current (mA) 40 30 20 10 0 -40 -20 0 20 40 60 80 100 Ambient temperature (°C)

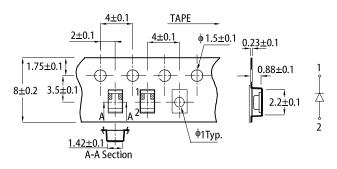
Luminous Intensity vs. Ambient Temperature



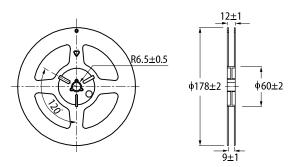
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units:mm)



REEL DIMENSION (units : mm)



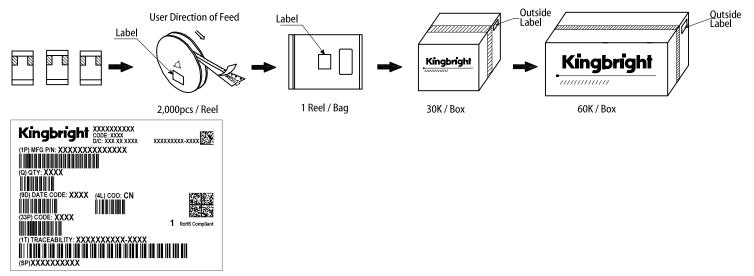
Notes:

- Don't cause stress to the LEDs while it is exposed to high temperature.
 The maximum number of reflow soldering passes is 2 times.
 Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

Kingbright

APT2012SYCK

PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

- The information included in this document reflects representative usage scenarios and is intended for technical reference only.
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications. 2.
- 3.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues. The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening liabilities, such as automotive or medical usage, please consult with Kingbright representative for further assistance. The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright. All design applications should refer to Kingbright application notes available at https://www.KingbrightUSA.com/ApplicationNotes 4.
- 5. 6.